

Green Products

Technical Data Data Sheet N1106, Rev. A

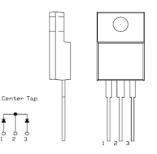
MBRF20100CTU SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

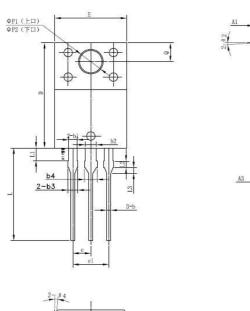
Features:

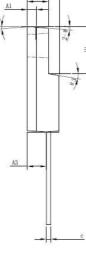
- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

Mechanical Dimensions (In mm):





SYMBOL	MIN.	TYP.	MAX.	
А	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A1 A2 A3	2.80	3.00	3.20 2.90	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.55	0.60	0.75	
C D E	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
H1 L L1 L2 L3	12.70	13.20	13.70	
L1	1.60	1.80	2.00 1.20	
L2	0.80	1.00	1.20	
	0.60	0.80	1.00	
ΦΡ1(上口)	3.30	3.50	3.70	
ΦΡ2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1 Θ2		5°		
Θ2		4°		
Θ3 Θ4		10°		
Θ4		5°		
Θ5		5°		

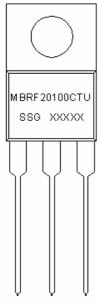
ITO-220AB(HD)



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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Where XXXXX is YYWWL

MBR	= Device Type
F	= Package type
20	= Forward Current (20A)
100	= Reverse Voltage (100V)
CTU	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Device	Package	Shipping
MBRF20100CTU	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	100	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =105°C, rectangular wave form	20	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.87	V
(per leg) *	V _{F2}	@ 10A, Pulse, T _J = 125 °C	0.77	V
Max. Reverse Current at DC condition (per leg)	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	1.0	mA
Max. Reverse Current (per leg) *	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	6.0	mA
Max. Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	250	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	ΤJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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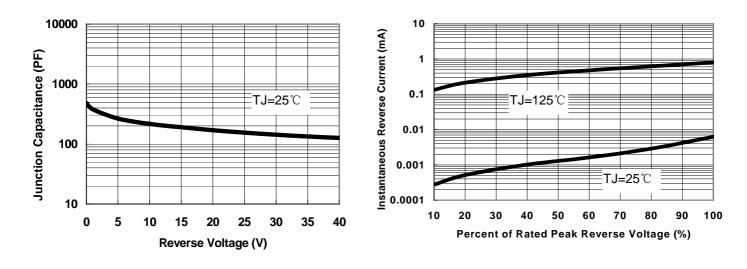


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

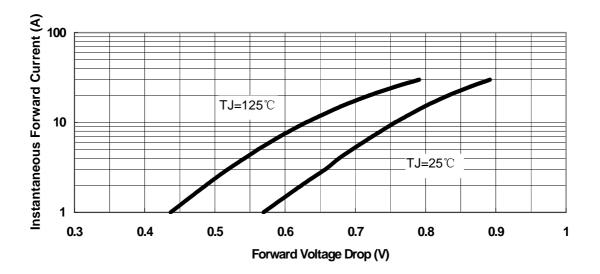


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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